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November 2008

FDZ391P P-Channel 1.5 V PowerTrench[®] Thin WL-CSP MOSFET -20 V, -3 A, 85 mΩ

Features

- Max $r_{DS(on)}$ = 85 m Ω at V_{GS} = -4.5 V, I_D = -1 A
- Max $r_{DS(on)}$ = 123 m Ω at V_{GS} = -2.5 V, I_D = -1 A
- Max $r_{DS(on)}$ = 200 m Ω at V_{GS} = -1.5 V, I_D = -1 A
- Occupies only 1.5 mm² of PCB area
- Ultra-thin package: less than 0.4 mm height when mounted to PCB
- RoHS Compliant

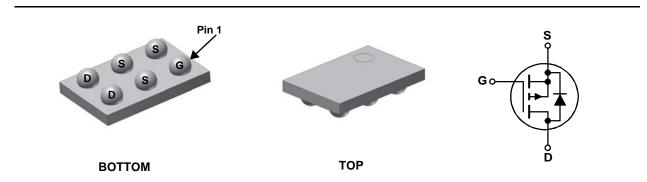


General Description

Designed on Fairchild's advanced 1.5 V PowerTrench process with state of the art "low pitch" **Thin** WLCSP packaging process, the FDZ391P minimizes both PCB space and $r_{DS(on)}$. This advanced WLCSP MOSFET embodies a breakthrough in packaging technology which enables the device to combine excellent thermal transfer characteristics, ultra-low profile packaging, low gate charge, and low $r_{DS(on)}$.

Applications

- Battery management
- Load switch
- Battery protection



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

| Symbol | Par | | Ratings | Units | | |
|-----------------------------------|-------------------------------------|------------------------|-----------|-------------|-----|--|
| V _{DS} | Drain to Source Voltage | | -20 | V | | |
| V _{GS} | Gate to Source Voltage | | | ±8 | V | |
| | Drain Current -Continuous | T _A = 25 °C | (Note 1a) | -3 | ۸ | |
| D | -Pulsed | | | -15 | Α | |
| D | Power Dissipation | T _A = 25 °C | (Note 1a) | 1.9 | 14/ | |
| P _D | Power Dissipation | T _A = 25 °C | (Note 1b) | 0.9 | W | |
| T _J , T _{STG} | Operating and Storage Junction Temp | perature Range | | -55 to +150 | °C | |

Thermal Characteristics

| $R_{	ext{	heta}JA}$ | Thermal Resistance, Junction to Ambient | (Note 1a) | 65 | °C/W |
|---------------------|---|-----------|-----|------|
| R_{\thetaJA} | Thermal Resistance, Junction to Ambient | (Note 1b) | 133 | C/VV |

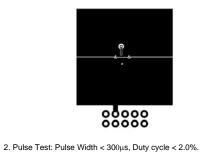
Package Marking and Ordering Information

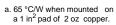
| Device Marking | Device | Package | Reel Size | Tape Width | Quantity |
|----------------|---------|-------------|-----------|------------|------------|
| 6 | FDZ391P | WL-CSP Thin | 7 " | 8 mm | 5000 units |

| Symbol | Parameter | Test Conditions | Min | Тур | Max | Units | |
|--|---|--|------|------|------|-------|--|
| Off Chara | cteristics | | | | | | |
| BV _{DSS} | Drain to Source Breakdown Voltage | I _D = -250 μA, V _{GS} = 0 V | -20 | | | V | |
| $\frac{\Delta BV_{DSS}}{\Delta T_J}$ | Breakdown Voltage Temperature Coefficient | $I_D = -250 \ \mu\text{A}$, referenced to 25 °C | | -12 | | mV/°C | |
| I _{DSS} | Zero Gate Voltage Drain Current | $V_{DS} = -16 V, V_{GS} = 0 V$ | | | -1 | μA | |
| I _{GSS} | Gate to Source Leakage Current | $V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$ | | | ±100 | nA | |
| On Chara | cteristics | | | | | | |
| V _{GS(th)} | Gate to Source Threshold Voltage | $V_{GS} = V_{DS}, I_{D} = -250 \ \mu A$ | -0.4 | -0.6 | -1.5 | V | |
| $\frac{\Delta V_{GS(th)}}{\Delta T_J}$ | Gate to Source Threshold Voltage Temperature Coefficient | $I_D = -250 \ \mu$ A, referenced to 25 °C | | 2 | | mV/°C | |
| r _{DS(on)} | Drain to Source On Resistance | V _{GS} = -4.5 V, I _D = -1 A | | 74 | 85 | - mΩ | |
| | | $V_{GS} = -2.5 \text{ V}, I_D = -1 \text{ A}$ | | 90 | 123 | | |
| | | $V_{GS} = -1.5 \text{ V}, \text{ I}_{D} = -1 \text{ A}$ | | 140 | 200 | | |
| | | V_{GS} = -4.5 V, I_{D} = -1 A T _J = 125 °C | | 100 | 123 | | |
| I _{D(on)} | On to State Drain Current | $V_{GS} = -4.5 \text{ V}, V_{DS} = -5 \text{ V}$ | -10 | | | Α | |
| 9 _{FS} | Forward Transconductance | $V_{DS} = -5 V, I_{D} = -1 A$ | | 7 | | S | |
| Dynamic | Characteristics | | | | | | |
| C _{iss} | Input Capacitance | N 40.4 M 0.4 | | 800 | 1065 | pF | |
| C _{oss} | Output Capacitance | V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz | | 155 | 205 | pF | |
| C _{rss} | Reverse Transfer Capacitance | | | 90 | 135 | pF | |
| R _g | Gate Resistance | f = 1 MHz | | 9 | | Ω | |
| Switching | g Characteristics | | | | | | |
| t _{d(on)} | Turn-On Delay Time | | | 11 | 20 | ns | |
| t _r | Rise Time | $V_{DD} = -10 \text{ V}, \text{ I}_{D} = -1 \text{ A}$ | | 10 | 20 | ns | |
| t _{d(off)} | Turn-Off Delay Time | $-$ V _{GS} = -4.5 V, R _{GEN} = 6 Ω | | 50 | 80 | ns | |
| t _f | Fall Time | | | 30 | 48 | ns | |
| Q _g | Total Gate Charge | V _{GS} = -4.5 V | | 9 | 13 | nC | |
| Q _{gs} | Gate to Source Gate Charge | $V_{DD} = -10 V$ | | 1 | | nC | |
| Q _{gd} | Gate to Drain "Miller" Charge | I _D = -1 A | | 2 | | nC | |
| Drain-Sou | urce Diode Characteristics | | | | | | |
| I _S | Maximum continuous Drain-Source Dio | de Forward Current | | | -1.1 | Α | |
| | Source to Drain Diade, Forward Voltage | | | 0.7 | 10 | V | |

| I _S | Maximum continuous Drain-Source Diode Forward Current | | | -1.1 | А |
|-----------------|---|---|------|------|----|
| V_{SD} | Source to Drain Diode Forward Voltage | V _{GS} = 0 V, I _S = -1.1 A (Note 2) | -0.7 | -1.2 | V |
| t _{rr} | Reverse Recovery Time | - I _F = -1 A, di/dt = 100 A/μs | 21 | | ns |
| Q _{rr} | Reverse Recovery Charge | $F = -1 A, avat = 100 A/\mu S$ | 5 | | nC |

Notes: 1. R_{θJA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{θJC} is guaranteed by design while R_{θCA} is determined by the user's board design.

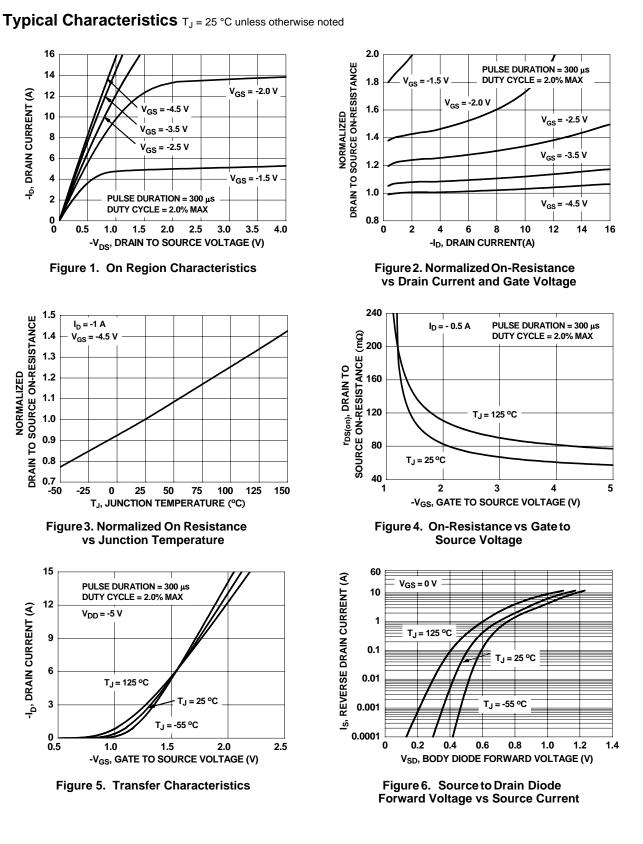




b. 133 °C/W when mounted on a minimum pad of 2 oz copper.



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FDZ391P Rev.B1

-I_D, DRAIN CURRENT (A)

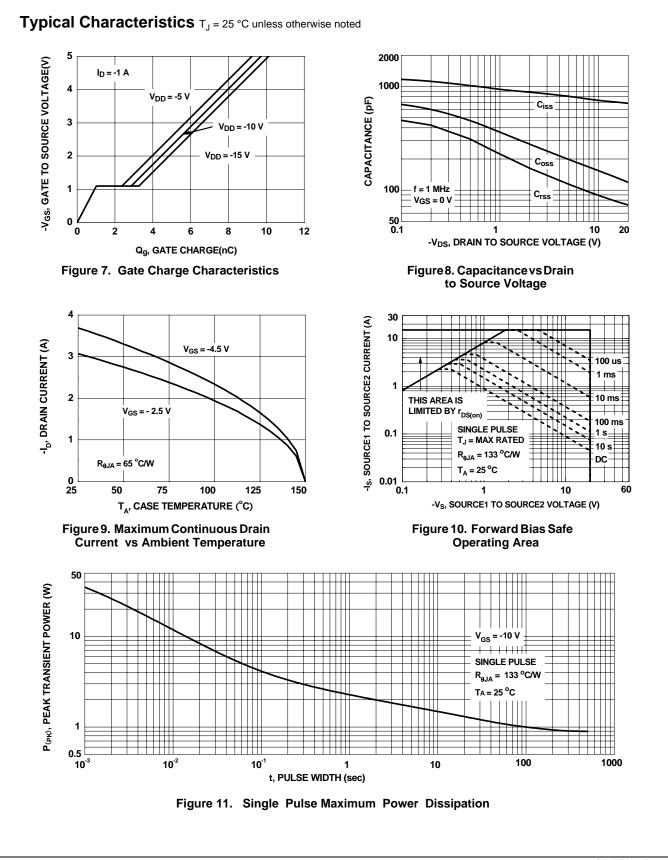
-I_D, DRAIN CURRENT (A)

DRAIN TO SOURCE ON-RESISTANCE

NORMALIZED

3

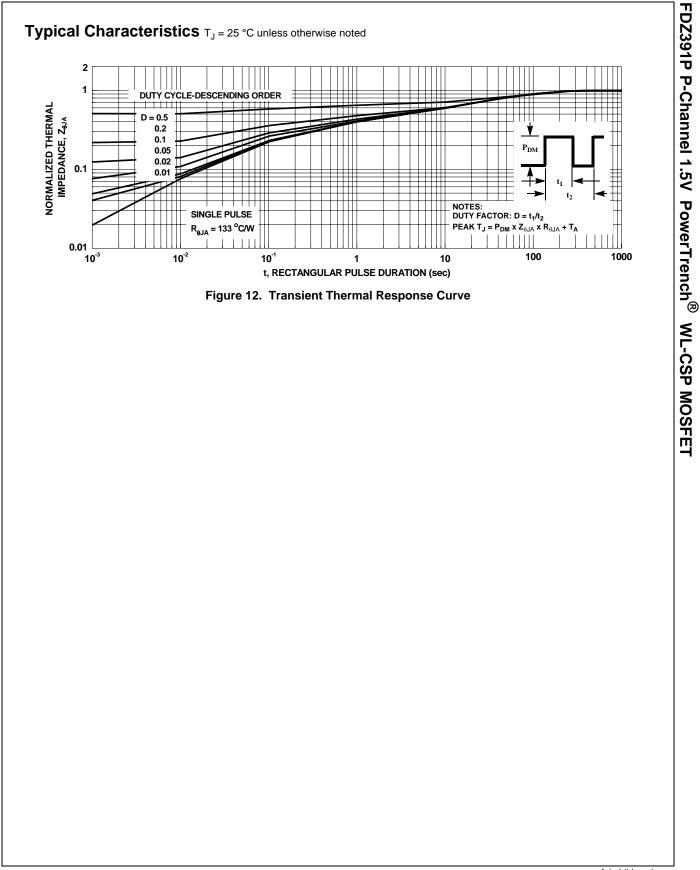
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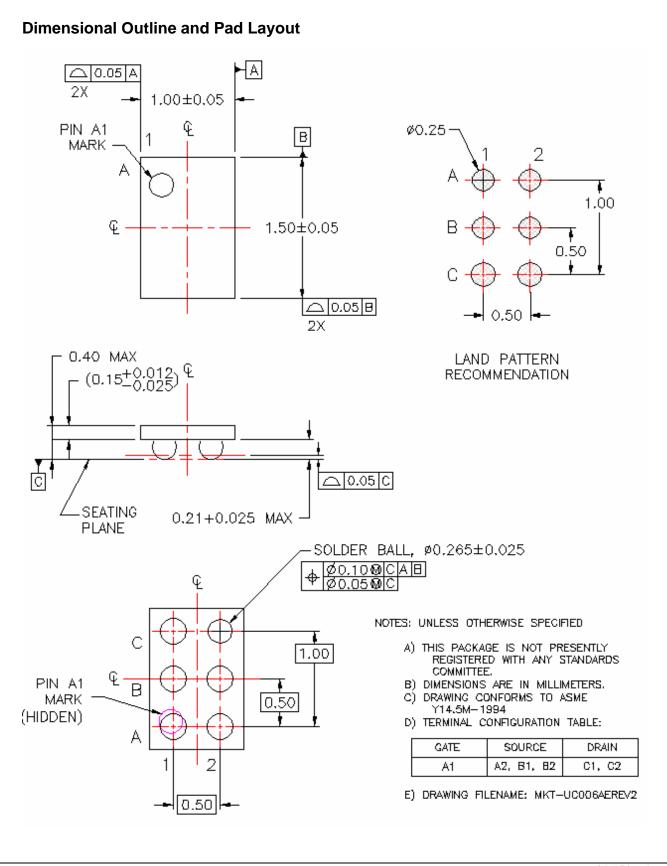


FDZ391P Rev.B1

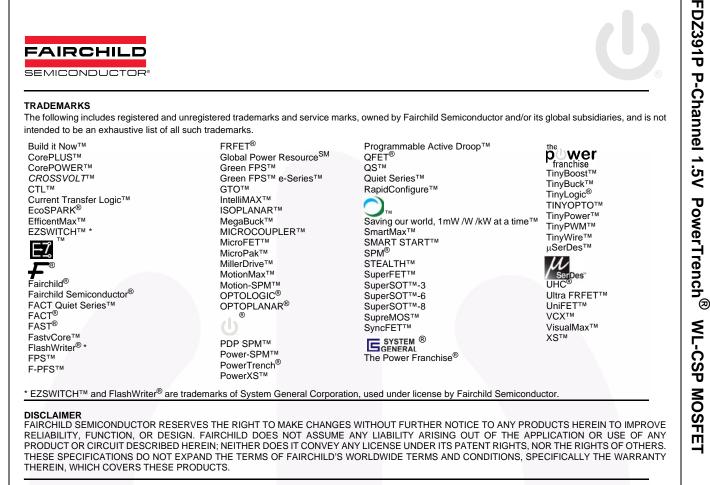
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|--------------------------|-----------------------|--|
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